









SN54HC257, SN54HC258, SN74HC257, SN74HC258 SCLS224C - DECEMBER 1982 - REVISED MARCH 2022

# SNx4HC257, SNx4HC258 Quadruple 2-Line to 1-Line Data Selectors/Multiplexers With **3-State Outputs**

#### 1 Features

- Wide operating voltage range of 2 V to 6 V
- High-current inverting outputs can drive up to 15 LSTTL loads
- Low power consumption, 80-µA max I<sub>CC</sub>
- 'HC257 typical  $t_{pd} = 9 \text{ ns}$
- 'HC258 typical  $t_{pd}$  = 12 ns
- ±6-mA output drive at 5 V
- Low input current of 1 µA max
- Provides bus interface from multiple sources in high-performance systems

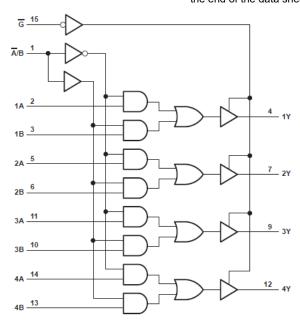
## 2 Description

The SNx4HC257 and '258 contain four data selectors/ multiplexers to select one of two data sources. All channels are controlled by the same address select  $(\overline{A}/B)$  input, and active-low strobe  $(\overline{G})$  input. A high level at the G terminal forces all outputs into the highimpedance state. The '257 has non-inverted outputs and the '258 has inverted outputs.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
SN74HC257D	SOIC (16)	9.90 mm × 3.90 mm
SN74HC257N	PDIP (16)	19.31 mm × 6.35 mm
SN74HC257NS	SO (16)	6.20 mm × 5.30 mm
SN74HC257PW	TSSOP (16)	5.00 mm × 4.40 mm
SN74HC258D	SOIC (16)	9.90 mm × 3.90 mm
SN74HC258N	PDIP (16)	19.31 mm × 6.35 mm
SN74HC258NS	SO (16)	6.20 mm × 5.30 mm
SN74HC258PW	TSSOP (16)	5.00 mm × 4.40 mm
SN54HC257J	CDIP (16)	24.38 mm × 6.92 mm
SNJ54HC257FK	LCCC (20)	8.89 mm × 8.45 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Pin numbers shown are for the D, J, N, NS, and PW packages.

**SN74HC257 Functional Block Diagram** 



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## **3 Revision History**

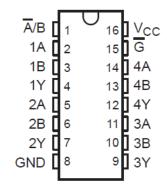
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision B (September 2003) to Revision C (March 2022)

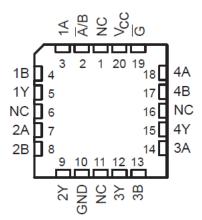
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## **4 Pin Configuration and Functions**



J, D, N, NS, or PW package 16-Pin CDIP, SOIC, PDIP, SO, TSSOP Top View



NC - No internal connection

FK package 20-Pin LCCC Top View



### **5 Specifications**

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		·	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	(V <sub>I</sub> < 0 or V <sub>I</sub> > V <sub>CC</sub> )		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	(V <sub>O</sub> = 0 to V <sub>CC</sub> )		±35	mA
	Continuous current through V <sub>C</sub>	<sub>C</sub> or GND		±70	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 5.2 Recommended Operating Conditions<sup>(1)</sup>

	·			54HC257, 54HC258			74HC257 74HC258		UNIT
			MIN	NOM MA	٩X	MIN	NOM	MAX	
V <sub>CC</sub>	Supply voltage		2	5	6	2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			1.5			
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15			V
		V <sub>CC</sub> = 6 V	4.2			4.2			
		V <sub>CC</sub> = 2 V			0.3			0.5	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V			0.9			1.35	V
		V <sub>CC</sub> = 6 V			1.2			1.8	
VI	Input voltage		0	V	СС	0		V <sub>CC</sub>	V
Vo	Output voltage		0	V	СС	0		V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V		10	00			1000	
t <sub>t</sub>	Input transition rise/fall time	V <sub>CC</sub> = 4.5 V		5	00			500	ns
		V <sub>CC</sub> = 6 V		4	00			400	
T <sub>A</sub>	Operating free-air temperature	•	-55	1	25	-40		85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

#### 5.3 Thermal Information

		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		16 PINS	16 PINS	16 PINS	16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance <sup>(1)</sup>	73	67	64	108	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



#### **5.4 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	V <sub>cc</sub>	Т,	<sub>A</sub> = 25°C		SN54HC SN54HC		SN74HC257, SN74HC258		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
		2 V	1.9	1.998		1.9		1.9		
	I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
$V_{OH}$		6 V	5.9	5.999		5.9		5.9		V
	I <sub>OH</sub> = −6 mA	4.5 V	3.98	4.3		3.7		3.84		
	I <sub>OH</sub> = -7.8 mA	6 V	5.48	5.8		5.2		5.34		
		2 V		0.002	0.1		0.1		0.1	
	I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	
$V_{OL}$		6 V		0.001	0.1		0.1		0.1	V
	I <sub>OL</sub> = 6 mA	4.5 V		0.17	0.26		0.4		0.33	
	I <sub>OL</sub> = 7.8 mA	6 V		0.15	0.26		0.4		0.33	
I	V <sub>I</sub> = V <sub>CC</sub> or 0	6 V		±0.1	±100		±1000		±1000	nA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or 0	6 V		±0.01	±0.5		±10		±5	μΑ
I <sub>cc</sub>	$V_I = V_{CC}$ or 0, $I_O = 0$	6 V			8		160		80	μΑ
C <sub>i</sub>		2 V to 6 V		3	10		10		10	pF

<sup>(1)</sup>  $V_I = V_{IH}$  or  $V_{IL}$ , unless otherwise noted.



### **5.5 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 50 pF (unless otherwise noted) (See Figure 6)

	PARAMETER	FROM	TO (OUTPUT)	Vcc	T <sub>A</sub> =	= 25°C		SN54HC2	257	SN74HC	257	UNIT
	FARAWETER	(INPUT)	10 (001701)	(V)	MIN	TYP	MAX	MIN N	MAX	MIN	MAX	ONII
				2		50	100		150		125	
		A or B	Any Y	4.5		10	20		30		25	
	Propagation dolay			6		9	17		25		21	no
t <sub>pd</sub>	Propagation delay			2		50	100		150		125	ns
		Ā/B	Any Y	4.5		10	20		30		25	
				6		9	17		25		21	
				2		75	150		225		190	
t <sub>en</sub>	Enable time	G	Any Y	4.5		15	30		45		38	ns
				6		13	26		38		32	
				2		75	150		225		190	
t <sub>dis</sub>	Diable time	G	Any Y	4.5		15	30		45		38	ns
				6		13	26		38		32	
				2		28	60		90		75	
t <sub>t</sub>	Transition time		Any Y	4.5		8	12		18		15	ns
				6		6	10		15		13	

## **5.5 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (See Figure 6)

	PARAMETER	FROM	TO (OUTPUT)	Vcc	TA	= 25°C		SN54HCT25	SN74HC257	UNIT
	PARAMETER	(INPUT)	10 (001701)	(V)	MIN	TYP	MAX	MIN MA	CAM MIM	
				2		75	150	24	5 190	
		A or B	Any Y	4.5		15	30	4	5 38	3
	Propagation delay			6		13	26	3	32	ns
t <sub>pd</sub>	Propagation delay			2		75	150	24	5 190	
		Ā/B	Any Y	4.5		15	30	4	5 38	B
				6		13	26	3	32	2
				2		100	200	30	250	
t <sub>en</sub>	Enable time	G	Any Y	4.5		24	40	6	50	ns
				6		18	34	5	1 43	3
				2		45	210	31	5 265	5
t <sub>t</sub>	Transition time		Any Y	4.5		17	42	6	3 53	ns
				6		13	36	5	3 45	5



### **5.5 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 50 pF (unless otherwise noted) (See Figure 6)

	PARAMETER	FROM	TO (OUTPUT)	Vcc	T <sub>A</sub>	= 25°C		SN54HC2	58	SN74HC	258	UNIT
	PARAMETER	(INPUT)	10 (001701)	(V)	MIN	TYP	MAX	MIN N	IAX	MIN	MAX	UNIT
				2		60	100		150		125	
		A or B	Any Y	4.5		13	20		30		25	
	Propagation dolay			6		12	17		25		21	20
t <sub>pd</sub>	Propagation delay			2		60	115		175		145	ns
		Ā/B	Any Y	4.5		13	23		35		29	
				6		12	20		30		25	
				2		70	150		225		190	
t <sub>en</sub>	Enable time	G	Any Y	4.5		15	30		45		38	ns
				6		13	26		38		32	
				2		75	150		225		190	
t <sub>dis</sub>	Diable time	G	Any Y	4.5		15	30		45		38	ns
				6		13	26		38		32	
				2		28	60		90		75	
t <sub>t</sub>	Transition time		Any Y	4.5		8	12		18		15	ns
				6		6	10		15		13	

## **5.5 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (See Figure 6)

	PARAMETER	FROM	TO (OUTPUT)	Vcc	TA	= 25°C		SN54H	C258	SN74H0	258	UNIT	
	PARAMETER	(INPUT)	10 (001701)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
				2		95	150		245		190		
		_	Any Y	Any Y	4.5		23	30		45		38	
	t <sub>pd</sub> Propagation delay			6	-	21	26		38		32		
<sup>L</sup> pd				2		95	165		240		210	ns	
			Any Y	Any Y	4.5		23	33		48		42	
				6		21	28		41		36		
				2		100	200		300		250		
t <sub>en</sub>	Enable time	G	Any Y	4.5	-	24	40		60		50	ns	
				6		18	34		51		43		
				2		45	210		315		265		
t <sub>t</sub>	Transition time	Any Y	Any Y	/	4.5		17	42		63		53	ns
				6		13	36		53		45		

## **5.6 Operating Characteristics**

 $T_A = 25^{\circ}C$ 

		Test Conditions	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per multiplexer	No load	40	pF



#### **6 Parameter Measurement Information**

 $t_{\text{pd}}$  is the maximum between  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$ 

 $t_{t}$  is the maximum between  $t_{\text{TLH}}$  and  $t_{\text{THL}}$ 

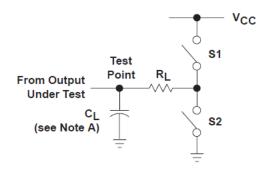


Figure 6-1. Load Circuit

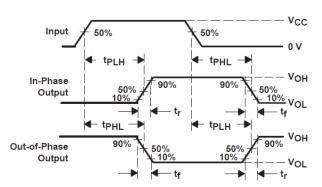


Figure 6-3. Voltage Waveforms
Propagation Delay and Output Transition Times

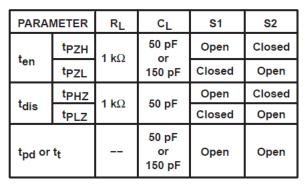


Figure 6-2.

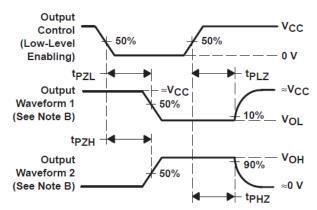


Figure 6-4. Voltage Waveforms
Enable and Disable Times For 3-State Outputs



Figure 6-5. Voltage Waveform Input Rise and Fall Times

- A. C<sub>1</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when diabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high except when diabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following charactersitics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r = 6$  ns,  $t_f = 6$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .



## 7 Detailed Description

### 7.1 Overview

These devices are designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable  $(\overline{G})$  input is at a high logic level.

To ensure the high-impedance state during power up or power down,  $\overline{G}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

### 7.2 Functional Block Diagram

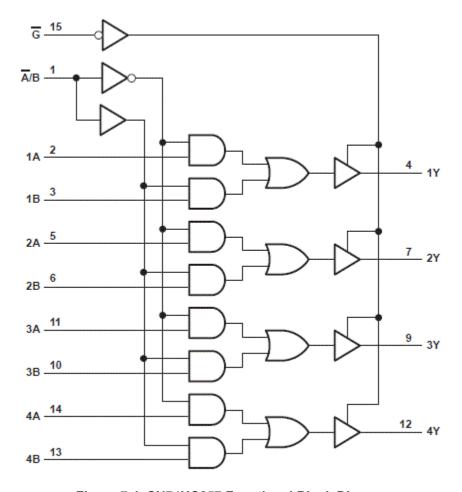


Figure 7-1. SN74HC257 Functional Block Diagram



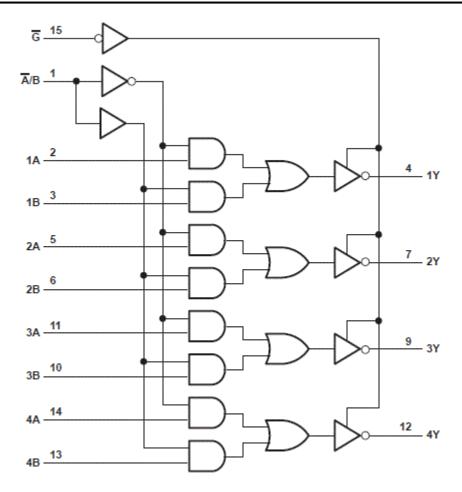


Figure 7-2. SN74HC258 Functional Block Diagram

### 7.3 Device Functional Modes

**Table 7-1. Function Table** 

	INP	UTS		OUTF	PUTY
G	Ā/B	'HC257	'HC258		
Н	Х	Х	Х	Z	Z
L	L	L	Х	L	Н
L	L	Н	Х	Н	L
L	Н	Х	L	L	Н
L	Н	Х	Н	Н	L



### 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

#### 9 Layout

#### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.



### 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### **10.1 Documentation Support**

#### 10.1.1 Related Documentation

#### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
85124012A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85124012A SNJ54HC 257FK
8512401EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512401EA SNJ54HC257J
SN54HC257J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC257J
SN54HC257J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC257J
SN74HC257D	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HC257
SN74HC257DR	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257DR.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257DRG4	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257DRG4.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257DT	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HC257
SN74HC257N	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC257N
SN74HC257N.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC257N
SN74HC257NSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257NSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257PW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-40 to 85	HC257
SN74HC257PWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257PWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC257PWR1G4	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC257
SN74HC258D	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-40 to 85	HC258
SN74HC258DR	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC258
SN74HC258DR.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC258
SN74HC258N	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC258N
SN74HC258N.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC258N
SN74HC258NSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC258
SN74HC258NSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC258
SN74HC258PW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-40 to 85	HC258
SN74HC258PWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC258





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7-Oct-2025

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74HC258PWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	(4) NIPDAU	(5) Level-1-260C-UNLIM	-40 to 85	HC258
SNJ54HC257FK	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85124012A SNJ54HC 257FK
SNJ54HC257FK.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85124012A SNJ54HC 257FK
SNJ54HC257J	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512401EA SNJ54HC257J
SNJ54HC257J.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512401EA SNJ54HC257J

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

## **PACKAGE OPTION ADDENDUM**

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HC257, SN74HC257:

■ Military: SN54HC257

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

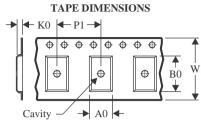
• Military - QML certified for Military and Defense Applications



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### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC257DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC257DRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC257NSR	SOP	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC257PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC257PWR1G4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC258DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC258NSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74HC258PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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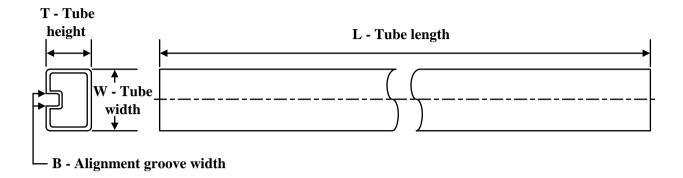
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC257DR	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC257DRG4	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC257NSR	SOP	NS	16	2000	353.0	353.0	32.0
SN74HC257PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74HC257PWR1G4	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74HC258DR	SOIC	D	16	2500	353.0	353.0	32.0
SN74HC258NSR	SOP	NS	16	2000	353.0	353.0	32.0
SN74HC258PWR	TSSOP	PW	16	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**

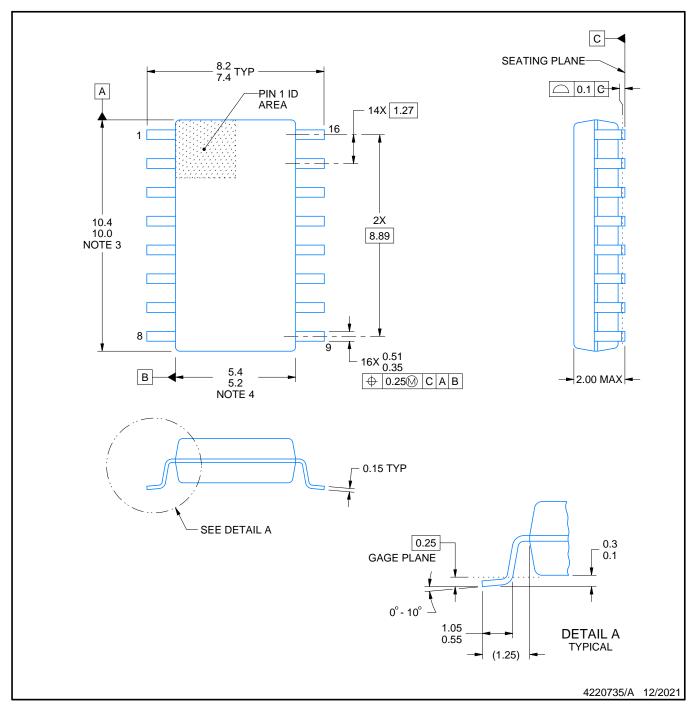


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
85124012A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74HC257N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC257N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC257N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC257N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC258N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC258N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC258N.A	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC258N.A	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC257FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC257FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA



SOP



#### NOTES:

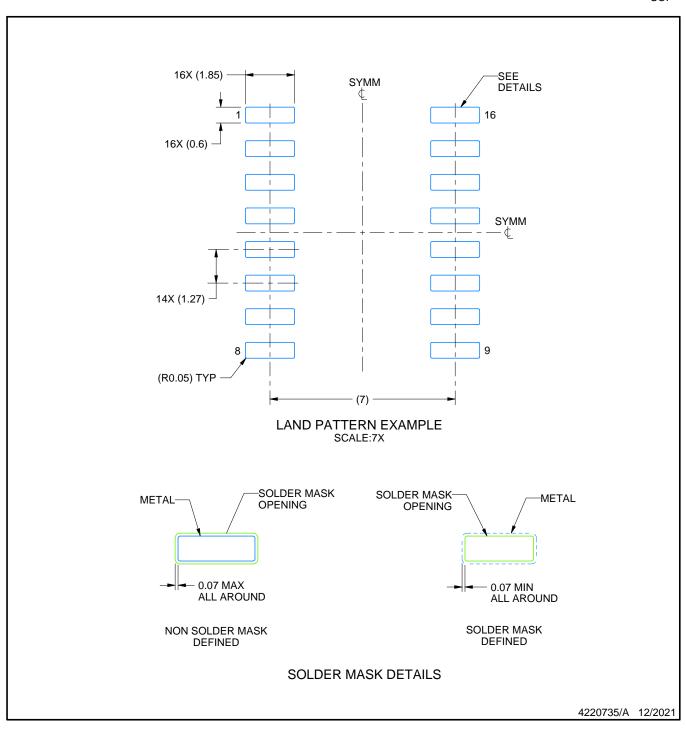
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF

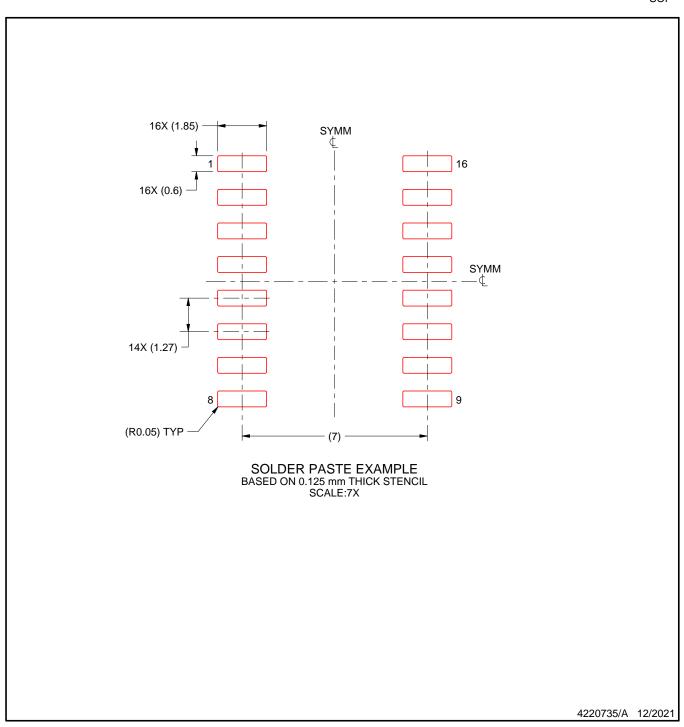


#### NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



NOTES:

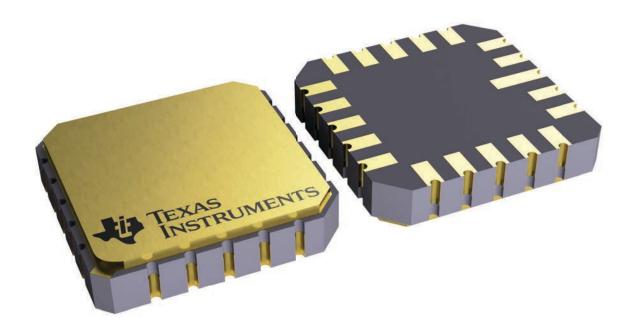
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



8.89 x 8.89, 1.27 mm pitch

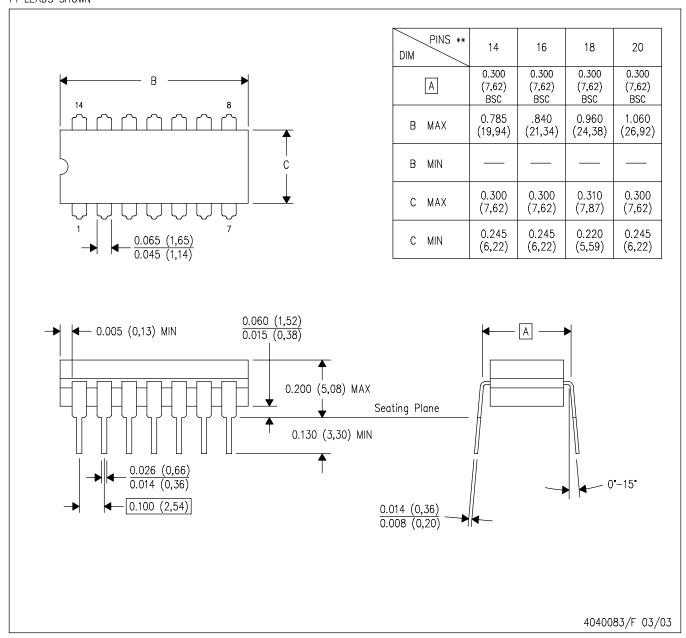
LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

#### 14 LEADS SHOWN

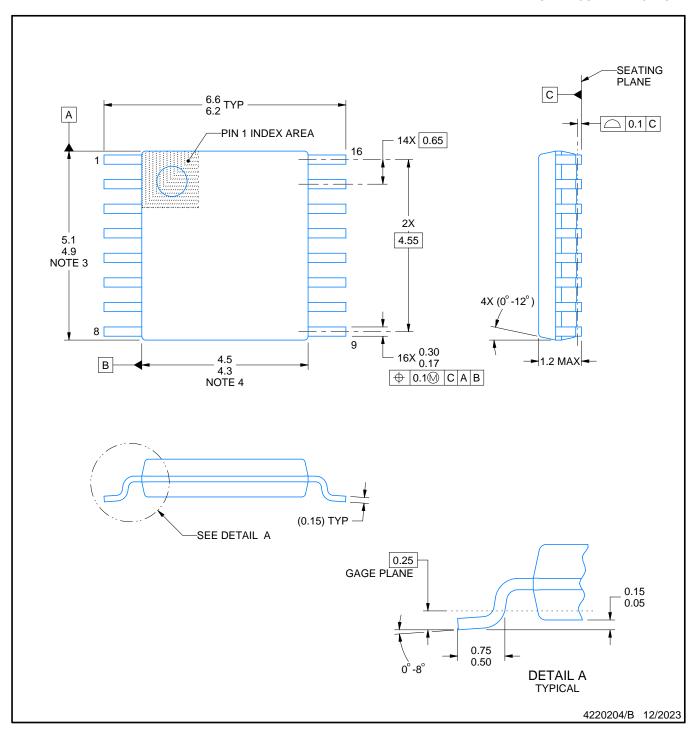


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



SMALL OUTLINE PACKAGE



#### NOTES:

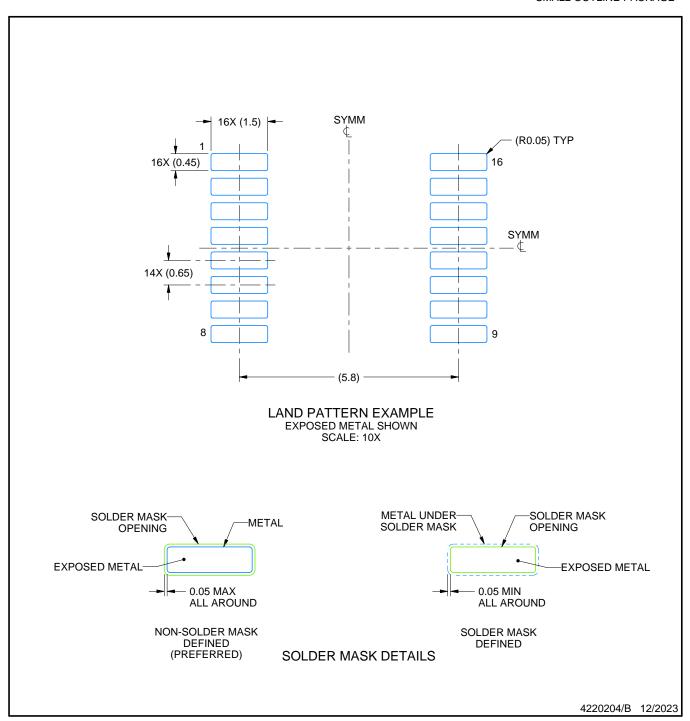
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

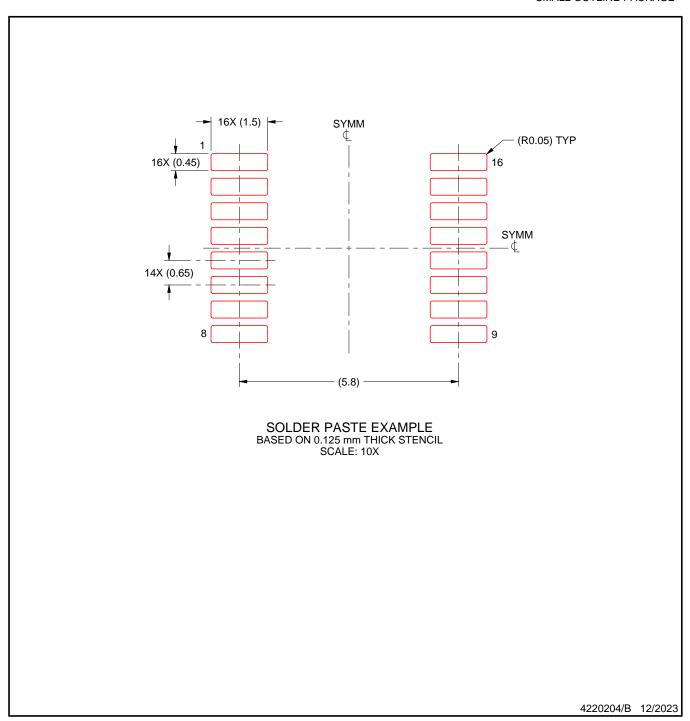


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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